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LIST OF ART CITED BY APPLICANT (Use several sheets if necessary)					APPLICANT J. Dennis Keller et al.		
					FILING DATE July 17, 1998	GROUP 2823	
U.S. PATENT DOCUMENTS							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	AA						
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FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Subclass	Translation
							Yes
	AL						No
	AM						
	AN						
	AO						
	AP						
OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)							
<i>MR</i>	AR		H. Shirai, et al., A 0.54μm <sup>2</sup> Self-Aligned, HSG Floating Gate Cell (SAHF Cell) for 256Mbit Flash Memories, 1995 IEEE pp27.1.1-27.1.4				
<i>MR</i>	AS		Yoshiaki S. Hisamune et al., A High Capacitive-Coupling Ratio (HiCR) Cell for 3 V-Only 64 Mbit and Future Flash Memories, 1993 IEEE pp2.3.1-2.3.4				
	AT						
EXAMINER	<i>Michelle Estrada</i>			DATE CONSIDERED		<i>1/12/05</i>	
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

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